# **DATASHEET**

*XPHASE3***TM POL CONTROL IC** 

# **DESCRIPTION**

The IR3513 Control IC provides overall control of a scalable number of phases along with an internal gate driver, current sense/sharing, and PWM. This allows the IR3513 to implement a stand-alone single-phase regulator or interface with additional Phase ICs to develop a power solution with any number of phases. With this arrangement, the final solution requires only 1 IC per phase to deploy 1 to X phases. Other approaches require a control IC plus 1 to X driver ICs or scalable "all-in-one" ICs that do not utilize all IC pins or circuitry leading to increased solution cost and size.

# **FEATURES**

- 0.8V reference supports 0.8V to 5.1V output voltage with +/-0.5% system set point accuracy
- Dynamic margin function provides  $\pm$  5 % reference offset
- 1 (stand-alone) to X phase operation with additional Phase IC
- Programmable 250 KHz to 9 Mhz daisy-chain digital phase timing provides a per phase switching frequency of 250 KHz to 1.5 MHz with no external components
- Differential remote sense amplifier with 100kohm input impedance
- IC bias linear regulator control with programmable output voltage and UVLO
- Programmable converter current limit during soft-start, hiccup with delay during normal operation
- Over voltage protection communicated to Phase ICs
- System over voltage signal protects against failures such as a shorted high side MOSFET
- Detection and protection of open remote sense lines
- Open control loop protection
- 7V/2A gate drivers (4A GATEL sink current)
- Integrated boot-strap synchronous PFET
- Small thermally enhanced 32L 5 x 5mm MLPQ package

# **APPLICATION CIRCUIT**



Figure 1 - IR3513 Application Circuit

# **ORDERING INFORMATION**



**PIN DESCRIPTION** 



# **PIN DESCRIPTION CONTINUED**



# **ABSOLUTE MAXIMUM RATINGS**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied.

Operating Junction Temperature...................0 to  $150^{\circ}$ C Storage Temperature Range……………………-65°C to 150°C MSL Rating………………………………………2 Reflow Temperature…………………………….260<sup>o</sup> C



Note: Maximum GATEH – SW = 8V, Maximum BOOST – GATEH = 8V

# **RECOMMENDED OPERATING CONDITIONS FOR RELIABLE OPERATION WITH MARGIN**

 $4.75V \leq$  VCCL ≤ 7.5V,  $4.75V \leq$  VCCP ≤ 7.5V,  $8V \leq$  VCC ≤ 16V, -0.3V ≤ VOSEN- ≤ 0.3V, 0 °C ≤ T<sub>J</sub> ≤ 125 °C, 7.75 kΩ ≤ ROSC ≤ 50 kΩ

# **ELECTRICAL CHARACTERISTICS**

The electrical characteristics involve the spread of values guaranteed within the recommended operating conditions. Typical values represent the median values, which are related to 25°C. 7.75K $\Omega \leq \text{Rosc} \leq 50.0 \text{ K}\Omega$ , Css/DEL = 0.1µF  $+/-10\%$ , C<sub>GATEH</sub> = 3.3nF, C<sub>GATEL</sub> = 6.8nF (unless otherwise specified).













**Note 1:** Guaranteed by design, but not tested in production

**Note 2:** VREF Output is trimmed to compensate for Error & Remote Sense Amp input offsets

**Note 3:** VCCL-0.5V or VCC – 2.5V, whichever is lower

# **SYSTEM SET POINT TEST**



Figure 2 - System Set Point Test Circuit

# **SYSTEM THEORY OF OPERATION**

### **PWM Control Method**

The PWM block diagram of the *XPhase*TM architecture is shown in Figure 3. Feed-forward voltage mode control with trailing edge modulation is used. A voltage-type error amplifier with high-gain (110dB) and wide-bandwidth is used for the control loop. It is not unity gain stable. The power-stage input voltage is sensed by the IR3513, and optional phase ICs, to provide feed-forward control. The PWM ramp slope will change with the input voltage and automatically compensate for changes in the input voltage. The input voltage can change due to variations in the silver box output voltage or due to the wire and PCB-trace voltage drop related to changes in load current.



Figure 3 - PWM Block Diagram

#### **Frequency and Phase Timing Control**

The oscillator system clock frequency is programmable from 500 kHz to 9 MHZ by an external resistor. The IR3513 system clock signal (CLKOUT) is connected to CLKIN of all the phase ICs. The phase timing of the phase ICs is controlled by the daisy chain loop, where the IR3513 phase clock output (PHSOUT) is connected to the phase clock input (PHSIN) of the first phase IC, and PHSOUT of the first phase IC is connected to PHSIN of the second phase IC, etc. The last phase IC (PHSOUT) is connected back to PHSIN of the control IC to complete the loop. During power up, the IR3513 sends out clock signals from both CLKOUT and PHSOUT pins and detects the feedback at PHSIN pin to determine the phase number and monitor any fault in the daisy chain loop. Figure 4 shows the phase timing for a four-phase converter. For single-phase operation, PHSOUT (pin 26) and PHSIN (pin 27) must be shorted together to prevent an Open Control Loop fault from occurring.





Figure 4 - Five Phase Oscillator Waveforms

#### **PWM Operation**

International

**IGR** Rectifier

Upon receiving the falling edge of a clock pulse, the PWM latch is set; the PWM ramp voltage begins to increase; the low side driver is turned off, and the high side driver is then turned on after the non-overlap time. When the PWM ramp voltage exceeds the error amplifier's output voltage the PWM latch is reset. This turns off the high side driver and then turns on the low side driver after the non-overlap time and activates the ramp discharge clamp. The ramp discharge clamp quickly discharges the PWM ramp capacitor to the output voltage of the share adjust amplifier in the phase IC until the next clock pulse.

The PWM latch is reset dominant allowing all phases to go to zero duty cycle within a few tens of nanoseconds in response to a load step decrease. Phases can overlap and go up to 100% duty cycle in response to a load step increase with turn-on gated by the clock pulses. An error amplifier output voltage greater than the common mode input range of the PWM comparator results in up to 100% duty cycle regardless of the voltage of the PWM ramp. This arrangement guarantees the error amplifier is always in control and can demand 0 to 100% duty cycle as required. It also favors response to a load step decrease, which is appropriate given the low output to input voltage ratio of most systems. The inductor current will increase much more rapidly than decrease in response to load transients. An additional advantage of the architecture is that differences in ground or input voltage at the phases have no effect on operation since the PWM ramps are referenced to VREF.

Figure 5 depicts PWM operating waveforms under various conditions.



Figure 5 - PWM Operating Waveforms

# **Body Braking™**

In a conventional synchronous buck converter, the minimum time required to reduce the current in the inductor in response to a load step decrease is;

$$
T_{SLEW} = \frac{L*(I_{MAX} - I_{MIN})}{V_O}
$$

The slew rate of the inductor current can be significantly increased by turning off the synchronous rectifier in response to a load step decrease. The switch node voltage is then forced to decrease until conduction of the synchronous rectifier's body diode occurs. This increases the voltage across the inductor from Vout to Vout +  $V_{\rm BODYDIODE}$ . The minimum time required to reduce the current in the inductor in response to a load transient decrease is now;

$$
T_{SLEW} = \frac{L*(I_{MAX} - I_{MIN})}{V_O + V_{BODYDDODE}}
$$

Since the voltage drop in the body diode is often higher than the output voltage, the inductor current slew rate can be increased by 2X or more. This patent pending technique is referred to as "body braking" and is accomplished through the "body braking comparator". If the error amplifier's output voltage drops below the VREF voltage or a programmable voltage, this comparator turns off the low side gate driver.

### **Lossless Average Inductor Current Sensing**

Inductor current can be sensed by connecting a series resistor and a capacitor network in parallel with the inductor and measuring the voltage across the capacitor, as shown in Figure 6. The equation of the sensing network is,

$$
v_C(s) = v_L(s) \frac{1}{1 + sR_{CS}C_{CS}} = i_L(s) \frac{R_L + sL}{1 + sR_{CS}C_{CS}}
$$

Usually the resistor Rcs and capacitor Ccs are chosen so that the time constant of Rcs and Ccs equals the time constant of the inductor which is the inductance L over the inductor DCR (RL). If the two time constants match, the voltage across Ccs is proportional to the current through L, and the sense circuit can be treated as if only a sense resistor with the value of RL was used. The mismatch of the time constants does not affect the measurement of inductor DC current, but affects the AC component of the inductor current.





Figure 6 - Inductor Current Sensing and Current Sense Amplifier

The advantage of sensing the inductor current versus high side or low side sensing is that actual output current being delivered to the load is obtained rather than peak or sampled information about the switch currents. The output voltage can be positioned to meet a load line based on real time information. Except for a sense resistor in series with the inductor, this is the only sense method that can support a single cycle transient response. Other methods provide no information during either load increase (low side sensing) or load decrease (high side sensing).

An additional problem associated with peak or valley current mode control for voltage positioning is that they suffer from peak-to-average errors. These errors will show in many ways but one example is the effect of frequency variation. If the frequency of a particular unit is 10% low, the peak to peak inductor current will be 10% larger and the output impedance of the converter will drop by about 10%. Variations in inductance, current sense amplifier bandwidth, PWM prop delay, any added slope compensation, input voltage, and output voltage are all additional sources of peak-to-average errors.

#### **Current Sense Amplifier**

A high speed differential current sense amplifier is included in both the IR3513 and optional phase ICs, as shown in Figure 6. Its gain is nominally 33 at 25ºC, and the 3850 ppm/ºC increase in inductor DCR should be compensated in the voltage loop feedback path.

The current sense amplifier can accept positive differential input up to 50mV and negative up to -10mV before clipping. The output of the current sense amplifier is summed with the VREF voltage and sent to other phases through an on-chip 3KΩ resistor connected to the ISHARE pin. The ISHARE pins of all the phases are tied together and the voltage on the share bus represents the average current through all the inductors and is used by the control IC for voltage positioning and current limit protection. The input offset of this amplifier is calibrated to +/- 1mV in order to reduce the current sense error.

The input offset voltage is the primary source of error for the current share loop. In order to achieve very small input offset error and superior current sharing performance, the current sense amplifier continuously calibrates itself. This calibration algorithm creates ripple on ISHARE bus with a frequency of fsw/896.

#### **Average Current Share Loop**

Current sharing between phases of the converter is achieved by the average current share loop in each phase IC. The output of the current sense amplifier is compared with average current at the share bus. If current in a phase is smaller than the average current, the share adjust amplifier of the phase will pull down the starting point of the PWM ramp thereby increasing its duty cycle and output current; if current in a phase is larger than the average current, the share adjust amplifier of the phase will pull up the starting point of the PWM ramp thereby decreasing its duty cycle and output current. The current share amplifier is internally compensated so that the crossover frequency of the current share loop is much slower than that of the voltage loop and the two loops do not interact.

ı

# **IR3513 THEORY OF OPERATION**

### **Block Diagram**

The IR3513 Block diagram is shown in Figure 7, and specific features are discussed in the following sections.



Figure 7 - Block Diagram

#### **VREF Control**

The MARGIN input comparators monitor the MARGIN pin and control the internal reference voltage whose output is sent to the VREF buffer amplifier. The output of the buffer amplifier is the VREF pin. The VREF voltage, input offsets of error amplifier and remote sense differential amplifier are post-package trimmed to provide 0.8% **system set-point** accuracy. The actual VREF voltage does not determine the system accuracy, which has a wider tolerance.

ı

The IR3513 can accept changes in the MARGIN input while operating and vary the VREF voltage accordingly. The slew rate of the voltage at the VREF pin can be adjusted by an external capacitor between VREF pin and LGND pin. A resistor connected in series with this capacitor is required to compensate the VREF buffer amplifier. Margin transitions result in a smooth analog transition of the VREF voltage and converter output voltage minimizing inrush currents in the input and output capacitors and overshoot of the output voltage.

#### **Remote Voltage Sensing**

VOSEN+ and VOSEN- are used for remote sensing and are connected directly to the load. The remote sense differential amplifier with high speed, low input offset and low input bias current ensures accurate voltage sensing and fast transient response.

#### **Start-up Sequence**

The IR3513 has a programmable soft-start function to limit the surge current during the converter start-up. A capacitor connected between the SS/DEL and LGND pins controls soft start timing, over-current protection delay and hiccup mode timing. A charge current of 52.5uA (typical) and discharge current of 4.5uA (typical) control the up and down slope of the voltage at the SS/DEL pin respectively.

Figure 8 shows normal converter start-up. If there is no fault, the SS/DEL pin will start charging. The error amplifier output EAOUT is clamped low until SS/DEL reaches 1.4V. The error amplifier will then regulate the converter's output voltage to match the SS/DEL voltage, less the 1.4V offset, until the converter output reaches the level determined by the VREF (0.8 V typically) inputs. The SS/DEL voltage continues to increase until it rises above 3.12V and allows the PG signal to be asserted. SS/DEL finally settles at 3.2V indicating the end of the soft start.

VCCL under voltage lock out, over current, as well as a low signal on the ENABLE input immediately sets the fault latch, which causes the EAOUT pin to drive low turning off the phase IC drivers. The PG pin also drives low, and SS/DEL begins to discharge until the voltage reaches 0.2V. If the fault has cleared the fault latch will be reset by the discharge comparator allowing a normal soft start to occur.

Other fault conditions, such as over voltage, open sense lines, and open daisy chain, set different fault latches, which start discharging SS/DEL, pull down EAOUT voltage and drive PG low. However, the latches can only be reset by cycling VCCL power.

If SS/DEL pin is pulled below 0.7V, the converter can be disabled.

ı



Figure 8 - Start-up sequence

### **Constant Over-Current Control during Soft Start**

The over-current limit threshold is set by a resistor connected between OCSET and VREF pins. If the IIN pin voltage, which is proportional to the average current plus VREF voltage, exceeds the OCSET voltage during soft start, the constant over-current control is activated.

Figure 9 shows the constant over-current control with delay during soft start. The delay is required since overcurrent conditions can occur as part of normal operation due to inrush current.

If an over-current occurs during soft start (before PG is asserted), the SS/DEL voltage is regulated by the over current amplifier to limit the output current below the threshold set by OCSET voltage. If the over-current condition persists after the delay time is reached, the fault latch will be set pulling the error amplifier's output low and inhibiting switching in the phase ICs. The SS/DEL capacitor will discharge until it reaches 0.2V and the fault latch is reset allowing a normal soft start to occur. If an over-current condition is again encountered during the soft start cycle, the constant over-current control actions will repeat and the converter will be in hiccup mode. The delay time is controlled by a counter, which is triggered by the oscillator. The counter values vary with switching frequency per phase in order to have a similar delay time for different switching frequencies.

#### **Over-Current Hiccup Protection after Soft Start**

The over current limit threshold is set by a resistor connected between OCSET and VREF pins. Figure 9 shows the constant over-current control with delay after PG is asserted. The delay is required since over-current conditions can occur as part of normal operation due to load transients or margin transitions.

If the IIN pin voltage, which is proportional to the average current plus VREF voltage, exceeds the OCSET voltage after PG is asserted, it will initiate the discharge of the capacitor at SS/DEL. If the over-current condition persists long enough for the SS/DEL capacitor to discharge below the 120mV offset of the delay comparator, the fault latch will be set pulling the error amplifier's output low and inhibiting switching in the phase ICs and de-asserting the PG signal. The output current is not controlled during the delay time. The SS/DEL capacitor will discharge until it reaches 200 mV and the fault latch is reset allowing a normal soft start to occur. If an over-current condition is again encountered during the soft start cycle, the over-current action will repeat and the converter will be in hiccup mode.



Figure 9 - Constant over-current control waveforms during and after soft start

# **Linear Regulator Output (VCCL)**

The IR3513 has a built-in linear regulator controller, and only an external NPN transistor is needed to create a linear regulator. The output voltage can be programmed between 4.75V and 7V by the resistor divider at VCCLFB pin. The regulator output powers the gate drivers of the phase ICs and circuits in the control IC, and the voltage is usually programmed to optimize the converter efficiency. The linear regulator can be compensated by a 4.7uF capacitor at the VCCL pin. As with any linear regulator, due to stability reasons, there is an upper limit to the maximum capacitor value that can be used at this pin and it is a function of the number of phases used in the multiphase architecture and their switching frequency. Figure 10 shows the stability plots for the linear regulator with 5 phases switching at 750 kHz.



Figure 10 **-** VCCL regulator stability with 5 phases and PHSOUT equals 750 kHz

#### **VCCL Under Voltage Lockout (UVLO)**

The IR3513 IC monitors both the Vcc and VCCL for under voltage condition. During power up, the fault latch will be reset if VCCL is above 94% (typical) of the voltage set by resistor divider at VCCLFB pin and the VCC exceeds 7.5V (typical). If VCCL voltage drops below 86% (typical) of the set value or VCC drops below 7V (typical), the fault latch will be set.

### **Power Good (PG)**

The PG pin is an open-collector output and should be pulled up to a voltage source through a resistor. During soft start, the PG remains low until the output voltage is in regulation and SS/DEL is above 3.12V. The PG pin becomes low if the fault latch, over voltage latch, open sense line latch, or open daisy chain latch is set. A high level at the PG pin indicates that the converter is in operation and has no fault, but does not ensure the output voltage is within the specification. Output voltage regulation within the design limits can logically be assured however, assuming no component failure in the system.

#### **Open Voltage Loop Detection**

The output voltage range of error amplifier is detected all the time to ensure the voltage loop is in regulation. If any fault condition forces the error amplifier output above VCCL-0.3V for 8 switching cycles, the fault latch is set. The fault latch can only be cleared by cycling power to VCCL.

#### **Load Current Indicator Output**

The IIN pin voltage represents the average current of the converter plus the VREF voltage. The load current information can be retrieved by a differential amplifier which subtracts the VREF voltage from the IIN voltage.

#### **Enable Input**

Pulling the ENABLE pin below 0.8V sets the Fault Latch and a voltage above 0.85V enables the soft start of the converter.

#### **Over Voltage Protection (OVP)**

Output over-voltage can occur during normal operation if a high side MOSFET short or other failure occurs. The over-voltage protection comparator monitors the OVSNS pin voltage. If the OVSNS pin voltage exceeds VREF by 85mV, as shown in Figure 11, the ROSC/OVP pin voltage is driven to V(VCCL) - 1V sending an over voltage signal to the host system. The ROSC/OVP pin can also be connected to a crowbar circuit, which pulls the converter input low in over voltage conditions.

The over voltage condition also sets the over voltage fault latch, which pulls the error amplifier output low to turn off the converter output. At the same time IIN pin (ISHARE of phase ICs) is pulled up to VCCL to communicate the over voltage condition to phase ICs (if present), as shown in Figure 11. The OVP circuit overrides the normal PWM operation and will fully turn-on the low side MOSFET within approximately 150ns. The low side MOSFET will remain on until ISHARE pin voltage drops below V(VCCL) - 800mV, which signals the end of over voltage condition. An over voltage fault condition is latched in the IR3513 and can only be cleared by cycling power to VCCL.

In the event of a high side MOSFET short before power up, the OVP flag is activated with as little supply voltage as possible, as shown in Figure 12. The OVSN pin is compared against a fixed voltage of 1.73V (typical) for OVP conditions at power-up. The ROSC/OVP pin will be pulled higher than 1.6V with VCCLDRV voltage as low as 1.8V. An external MOSFET or comparator should be used to disable the silver box, activate a crowbar, or turn off the supply source. The 1.8V threshold is used to prevent false over-voltage triggering caused by pre-charging of output capacitors.

# International **IGR** Rectifier

# **REPLACEMENT PRODUCT – IR3513ZMTRPBF RIPLACEMENT PRODUCT – IR3513ZMTRPBF NOT RECOMMENDED FOR NEW DESIGNS**









Pre-charging of the converter output voltage may trigger OVP. If the converter output is pre-charged above 1.73V as shown in Figure 17, ROSC/OVP pin voltage will be higher than 1.6V when VCCLDRV voltage reaches 1.8V. ROSC/OVP pin voltage will be VCCLDRV-1V and rise with VCCLDRV voltage until VCCL is above UVLO threshold, after which ROSC/OVP pin voltage will be VCCL-1V. The converter cannot start unless the over voltage condition stops and VCCL is cycled. If the converter output is pre-charged 130mV above VREF but lower than 1.73V, as shown in Figure 17, the converter will soft start until SS/DEL voltage is above 3.92V (4.0V-0.08V). Then, over voltage comparator is activated and fault latch is set.







Figure 14 - Over-voltage protection with pre-charging converter output VREF + 0.13V <Vo < 1.73V

International **IGR** Rectifier

During a MARGIN up to a MARGIN down event (80mV excursion on VREF), OVP may be triggered since the OVP threshold is a fixed 85mV above VREF. This can occur due to large output capacitance and light/no load operation where the output voltage remains high while the OVP threshold falls.

ı

The overall system must be considered when designing for OVP. In many cases the over-current protection of the AC-DC or DC-DC converter supplying the multiphase converter will be triggered and provide effective protection without damage as long as all PCB traces and components are sized to handle the worst-case maximum current. If this is not possible, a fuse can be added in the input supply to the multiphase converter.

#### **Error Amplifier Head Room Control**

In high converter output voltage applications, there may not be enough head room in error amplifier and current sense amplifiers of phase ICs when VCC is just above UVLO start and stop thresholds. A head room control circuit is implemented to ensure  $V(VCC) - V(VO) > 2.5V$  by sourcing extra current to the resistor connecting to FB pin. When this circuit is activated, the converter voltage is lower than the required and therefore the PG is also driven low.

#### **Open Remote Sense Line Protection**

If either remote sense line VOSEN+ or VOSEN- or both is open, the output of remote sense amplifier (VOUT) drops. The IR3513 monitors VO pin voltage continuously. If VOUT voltage is lower than 200 mV, two separate pulse currents are applied to VOSEN+ and VOSEN- pins respectively to check if the sense lines are open. If VOSEN+ is open, a voltage higher than 90% of V(VCCL) will be present at VOSEN+ pin and the output of open line detect comparator will be high. If VOSEN- is open, a voltage higher than 400mV will be present at VOSEN- pin and the output of open line detect comparator will be high. The open sense line fault latch is set, which pulls error amplifier output low immediately and shut down the converter. SS/DEL voltage is discharged, and the fault latch can only be reset by cycling VCCL power.

#### **Open Daisy Chain Protection**

IR3513 checks the daisy chain every time it powers up. It starts a daisy chain pulse on the PHSOUT pin and detects the feedback at PHSIN pin. If no pulse comes back after 30 CLKOUT pulses, the pulse is restarted again. If the pulse fails to come back the second time, the open daisy chain fault is registered, and SS/DEL is not allowed to charge. The fault latch can only be reset by cycling the power to VCCL.

After powering up, the IR3513 monitors PHSIN pin for a phase input pulse equal or less than the number of phases detected. If PHSIN pulse does not return within the number of phases in the converter, another pulse is started on PHSOUT pin. If the second started PHSOUT pulse does not return on PHSIN, an open daisy chain fault is registered.

#### **Phase Number Determination**

After a daisy chain pulse is started, the IR3513 checks the timing of the input pulse at PHSIN pin to determine the phase number.

#### **Output Voltage Under-voltage Monitoring**

The IR3513 compares the FB pin to a voltage, V, equal to 0.897×Vref. If the FB pin is 50mV (typical) below the aforementioned V, the output voltage under-voltage monitor will trigger, pulling the PG pin low. The output voltage under-voltage monitor does not effect switching of the phases or soft start.

ı

### **Fault Table**

The Fault Table below describes the different faults that can occur and how IR3513 would react to protect the supply and the load from possible damage. The fault types that can occur are listed in row 1. Row 2 has the method that a fault is cleared. The first 4 faults are latched in the UV fault latch and the VCCL power has to be recycled by switching off the input and switching it back on for the converter to work again. The rest of the faults (except for UVLO Vout) are latched in the SS fault latch and do not need to recycle the VCCL power in order for IR3513 to resume operation. IR3513 will automatically resume operation when these fault conditions no longer apply in the system. Most of the faults disable the error amplifier (EA) and discharge the soft start capacitor. All the faults flag PGood. PGood returns back to high when the faults are cleared. The delay row shows how long it takes IR3513 to react after detecting a fault condition. Delays are provided to minimize the possibility of nuisance faults.

#### **Fault table**



# **APPLICATIONS INFORMATION**



Figure 15 - Scalable Master (IR3513) & Slave (IR3505) POL modules with programmable output voltage and redundant OVP sense

# **DESIGN PROCEDURES**

#### **IR3513 EXTERNAL COMPONENTS**

#### **Oscillator Resistor** *Rosc*

The oscillator of IR3513 generates square-wave pulses to synchronize the phase ICs. The switching frequency of the each phase converter equals the PHSOUT frequency, which is set by the external resistor ROSC according to the curve in Figure 16. The CLKOUT frequency equals the switching frequency multiplied by the phase number.



Figure 16 Operational Frequency vs Rosc Resistor

#### **Soft Start Capacitor** *CSS/DEL*

The CSS/DEL capacitor programs four different time parameters, i.e. soft start delay time, soft start time, VR ready delay time and over-current fault latch delay time after VR ready. These parameters can be calculated with the following equations:

$$
T_{ssdelay} = \frac{C_{SS/DEL} * 1.4}{I_{CHG}} = \frac{C_{SS/DEL} * 1.4}{52.5 * 10^{-6}}
$$
(1)

$$
T_{ss} = \frac{C_{SS/DEL} * Vref}{I_{CHG}} = \frac{C_{SS/DEL} * 0.8}{52.5 * 10^{-6}}
$$
 (2)

$$
T_{PG\_delay} = \frac{C_{SS/DEL} * (3.12 - Vref)}{I_{CHG}} = \frac{C_{SS/DEL} * 2.32}{52.5 * 10^{-6}}
$$
(3)

$$
T_{OC\_delay} = \frac{C_{SS/DEL} * 120 * 10^{-3}}{I_{CHG}} = \frac{C_{SS/DEL} * 120 * 10^{-3}}{52.5 * 10^{-6}}.
$$
 (4)

#### **Over Current Setting Resistor** *ROCSET*

The inductor DC resistance is utilized to sense the inductor current. The copper wire of the inductor has a constant temperature coefficient of 3850 ppm/°C, and therefore the maximum inductor DCR can be calculated from (5). RL\_MAX and RL\_ROOM are the inductor DCR\_value at maximum temperature (TL\_MAX) and room temperature (T\_ROOM), respectively.

$$
R_{L\_MAX} = R_{L\_ROM} * [1 + 3850 * 10^{-6} * (T_{L\_MAX} - T_{ROM})]
$$
(5)

The total input offset voltage (VCS\_TOFST) of current sense amplifier in phase ICs is the sum of input offset (VCS\_OFST) of the amplifier itself and that created by the amplifier input bias current flowing through the current sense resistor RCS.

$$
V_{CS\_TOFST} = V_{CS\_OFST} + I_{CSIN+} * R_{CS}
$$
\n
$$
\tag{6}
$$

The over-current limit is set by the external resistor, ROCSET, as defined in (7), where ILIMIT is the required over current limit. IOCSET, the bias current of OCSET pin, changes with switching frequency set by resistor ROSC and is determined by equation (9). GCS is the gain of the current sense amplifier. In a multiphase architecture the peak to peak ripple of the net inductor current is much smaller than the stand alone phase due to interleaving. The ratio of the peak to average current in this case can be approximated using (8).

$$
R_{OCSET} = \left[\frac{I_{LIMIT}}{n} * R_{L_{MAX}} * (1 + K_P) + V_{CS_{TOST}}\right] * G_{CS} / I_{OCSET}
$$
 (7)

$$
K_{P} = \frac{\left[V_{I} \cdot D \cdot (1-D) \cdot n \cdot (D - \frac{m}{n}) \cdot (\frac{m+1}{n} - D)\right]}{(I_{LMMT}/n) \cdot L \cdot f_{sw} \cdot 2 \cdot D \cdot (1-D)}
$$
(8)

$$
Iocset = \frac{000}{Rosc(K\Omega)}\tag{9}
$$

**Where** 

 $I<sub>LIMIT</sub>$ =Maximum over current limit n=Number of phases  $K_P$ =Ratio of the peak to average current for the inductor  $G<sub>CS</sub>=Gain$  of the current sense amplifier  $I_{OCSET}$ = Determined by the ROSC and given (9)  $D=V_0/V_1$ m=Maximum integer that doesn't exceed (n\*D)

#### **Vout Programming Resistor** *RFB1* **and** *RFB3*

The Feedback pin (FB) is connected to an external resistor divider to set the output voltage. The error amplifier has a 0.8 V reference (Typical) and the output voltage is determined by selecting resistor divider values (See Figure 1).

$$
R_{FB3} = \frac{R_{FB1} * 0.8}{Vout - 0.8}
$$
 (10)

#### **VCCL Programming Resistor** *RVCCLFB1* **and** *RVCCLFB2*

Since VCCL voltage is proportional to the MOSFET gate driver loss and inversely proportional to the MOSFET conduction loss, the optimum voltage should be chosen to maximize the converter efficiency. VCCL linear regulator consists of an external NPN transistor, a ceramic capacitor and a programmable resistor divider. Pre-select RVCCLFB1, and calculate RVCCLFB2 from (11).

$$
R_{VCCLFB2} = \frac{R_{VCCLFB1} * 1.19}{VCCL - 1.19}
$$
\n(11)

#### **VCCL Capacitor** *CVCCL*

The capacitor is selected based on the stability requirement of the linear regulator and the load current to be driven. The linear regulator supplies the bias and gate drive current of the phase ICs. A 4.7uF normally ensures stable VCCL performance for most applications.

#### **VCCL Regulator Drive Resistor** *RVCCLDRV*

 The drive resistor is primarily dependent on the load current requirement of the linear regulator and the minimum input voltage requirements. The following equation gives an estimate of the average load current of the switching phase ICs.

$$
I_{drive \_{avg}} = (Q_{gb} + Q_{gt}) \cdot n + I_{VCL \_ PHS} \cdot (n-1) + I_{VCL \_ C}
$$
 (12)

 $Q_{gb}$  and  $Q_{gt}$  are the gate charge of the top and bottom FET,  $I_{VCL\_PHS}$  is the VCCL current of the phase IC-s,  $I_{\text{VCL C}}$  is the VCCL current of the controller and n is the number of phases. For a minimum input voltage and a maximum VCCL, the maximum  $R_{VCCLDRV}$  required to use the full pull-down current of the VCCL driver is given by

$$
R_{\text{VCCLDRV}} = \frac{V_I \left(\text{min}\right) - 0.7 - \text{VCCL}(\text{max})}{I_{\text{drive\_avg}} / \beta_{\text{min}}} \tag{13}
$$

Due to limited pull down capability of the VCCLDRV pin, make sure the following condition is satisfied.

$$
\frac{V_t(\max) - 0.7 - VCCL(\min)}{R_{vCCLDRV}} < 10mA \tag{14}
$$

In the above equation,  $V_1$  min) and  $V_1$  max) is the minimum and maximum anticipated input voltage. If the above condition is not satisfied there is a need to use a device with higher  $\beta_{\text{min}}$  or Darlington configuration can be used instead of a single NPN transistor.

#### **Inductor Current Sensing Capacitor** *CCS* **and Resistor** *RCS*

 $R_{CS}$ 

The DC resistance of the inductor is utilized to sense the inductor current. Usually the resistor RCS and capacitor CCS in parallel with the inductor are chosen to match the time constant of the inductor, and therefore the voltage across the capacitor CCS represents the inductor current. If the two time constants are not the same, the AC component of the capacitor voltage is different from that of the real inductor current. The time constant mismatch does not affect the average current sharing among the multiple phases, but affects the current signal ISHARE.

Measure the inductance L and the inductor DC resistance RL. Pre-select the capacitor CCS and calculate RCS as follows.

$$
R_{CS} = \frac{L/R_L}{C_{CS}}\tag{15}
$$

#### **Bootstrap Capacitor** *CBST*

Depending on the duty cycle and gate drive current of the phase IC, a capacitor in the range of 0.1uF to 1uF is needed for the bootstrap circuit.

#### **Decoupling Capacitors for Phase IC**

0.1uF-1uF decoupling capacitors are required at VCC and VCCL pins of phase ICs.

#### **Over-voltage Resistors** *ROV1* **and** *ROV2*

The over-voltage resistors are used to set the voltage at the OVSNS pin. If the voltage of the OVSNS pin exceeds VREF by 85mV then the over-voltage protection will be activated and the error amplifier voltage will be pulled down turning the converter off. The over-voltage fault is latched, which means that the power to the converter has to be recycled for the fault to clear. Choose VOVSNS a certain value ∆V below VREF. VREF is typically 0.8 V. The over-voltage threshold will then be ∆V+85mV. Select *ROV1. ROV2* is calculated based on (16).

$$
R_{OV2} = \frac{VOV S N S * R_{OV1}}{V_{OUT} - VOV S N S}
$$
\n(16)

#### **VREF Slew Rate Programming Capacitor** *CVREF* **and Resistor** *RVREF*

The slew rate of MARGIN down-slope can be programmed by the external capacitor CVREF as defined in (17), where ISINK is the sink current of the VREF pin. The slew rate of MARGIN up-slope is the same as that of downslope. The resistor RVREF is used to compensate the VREF circuit and can be calculated as shown in (18).

$$
C_{VREF} = \frac{I_{SINK}}{SR_{MARGIN}} = \frac{132 * 10^{-6}}{SR_{MARGIN}}
$$
\n
$$
R_{VREF} = 0.5 + \frac{3.2 * 10^{-15}}{C_{VREF}^2}
$$
\n(18)

#### **Type III Compensation**

Choose the crossover frequency fc between 1/10 and 1/5 of the switching frequency per phase, the desired phase margin θc and Rfb1 (see Figure 17). Determine the component values based on the equations below. wc is 2\*π\*fc (the crossover angular frequency), Le is the equivalent inductance of the converter, C is the output capacitance, Rst is the total equivalent resistance in series with the inductor, Rc is the output capacitance ESR and R is the load resistance.

$$
Ccp = \frac{1}{K \cdot Rf b1} \tag{19}
$$

$$
Rcp = \frac{1}{Ccp \cdot wz1} \tag{20}
$$

$$
Cf b = \frac{1}{wz^2 \cdot Rf b1} \tag{21}
$$

$$
Ccp1 = \frac{1}{wp2 \cdot Rcp}
$$
 (22)

$$
Rf b2 = \frac{1}{wp1 \cdot Cfb} \tag{23}
$$

where,

$$
wz1 = \frac{wc}{10}
$$
 (24)

$$
wz2 = wc \cdot \sqrt{\frac{1 - \sin(\theta c)}{1 + \sin(\theta c)}}
$$
 (25)

$$
wp1 = wc \cdot \sqrt{\frac{1 + \sin(\theta c)}{1 - \sin(\theta c)}}
$$
 (26)

$$
wp2 = 1.4 \cdot wp1 \tag{27}
$$

$$
K = \frac{(wc^4 \cdot t_4^2 + wc^2 \cdot t_2^2)((1 - b \cdot wc^2)^2 + a^2 \cdot wc^2)(R + Rst)}{Gpwm \cdot H \cdot t_5 \cdot t_6 \cdot R}
$$
 (28)

where Gpwm is the gain of the PWM generator, H is the gain of the feedback filter and

$$
a = \frac{Le + C(R \cdot Rst + R \cdot Rc + Rst \cdot Rc)}{R + Rst}
$$
\n(29)

$$
b = Le \cdot C \frac{R + Rc}{R + Rst} \tag{30}
$$

$$
t_1 = 1 - \frac{wc^2}{wz1 \cdot wz2} \tag{31}
$$

$$
t_2 = 1 - \frac{wc^2}{wp1 \cdot wp2}
$$
 (32)

$$
t_3 = \frac{1}{wz1} + \frac{1}{wz2} \tag{33}
$$

$$
t_4 = \frac{1}{wp1} + \frac{1}{wp2}
$$
 (34)

$$
t_5 = \sqrt{(1 - b \cdot wc^2 + wc^2 \cdot RC \cdot C \cdot a)^2 + wc^2 (Rc \cdot C(1 - b \cdot wc^2) - a)^2}
$$
 (35)  

$$
t_7 = \sqrt{(1 - b \cdot wc^2 + wc^2 + wc^2 (1 - b \cdot wc^2) + mc^2 (1 - b \cdot wc^2)} = (36)
$$

$$
t_6 = \sqrt{wc^4 (t_2 \cdot t_3 - t_1 \cdot t_4)^2 + wc^2 (t_1 \cdot t_2 + wc^2 \cdot t_3 \cdot t_4)^2}
$$
 (36)





# **LAYOUT GUIDELINES**

The following layout guidelines are recommended to reduce the parasitic inductance and resistance of the PCB layout, therefore minimizing the noise coupled to the IC.

- Dedicate at least one middle layer for a ground plane.
- Separate analog bus (EAIN, DACIN and ISHARE) from digital bus (CLKIN, PHSIN, and PHSOUT) to reduce the noise coupling.
- Connect PGND to LGND pins to the ground plane through vias
- Place current sense resistors and capacitors (RCS and CCS) close to IC. Use Kelvin connection for the inductor current sense wires, but separate the two wires by ground polygon. The wire from the inductor terminal to CSIN- should not cross over the fast transition nodes, i.e. switching nodes, gate drive outputs and bootstrap nodes.
- Place the IC, gate drive side as close as possible to the MOSFETs to reduce the parasitic resistance and inductance of the gate drive paths.
- Place the input ceramic capacitors close to the drain of top MOSFET and the source of bottom MOSFET.



#### **PCB Metal and Component Placement**

- Lead land width should be equal to nominal part lead width. The minimum lead to lead spacing should  $be \geq 0.2$ mm to minimize shorting.
- Lead land length should be equal to maximum part lead length + 0.3 mm outboard extension + 0.05mm inboard extension. The outboard extension ensures a large and inspectable toe fillet, and the inboard extension will accommodate any part misalignment and ensure a fillet.
- Center pad land length and width should be equal to maximum part pad length and width. However, the minimum metal to metal spacing should be ≥ 0.17mm for 2 oz. Copper (≥ 0.1mm for 1 oz. Copper and ≥ 0.23mm for 3 oz. Copper)
- Four 0.30mm diameter vias shall be placed in the center of the pad land and connected to ground to minimize the noise effect on the IC.
- No PCB traces should be routed nor vias placed under any of the 4 corners of the IC package. Doing so can cause the IC to rise up from the PCB resulting in poor solder joints to the IC leads.



### **Solder Resist**

- The solder resist should be pulled away from the metal lead lands by a minimum of 0.06mm. The solder resist mis-alignment is a maximum of 0.05mm and it is recommended that the lead lands are all Non Solder Mask Defined (NSMD). Therefore pulling the S/R 0.06mm will always ensure NSMD pads.
- The minimum solder resist width is 0.13mm.
- At the inside corner of the solder resist where the lead land groups meet, it is recommended to provide a fillet so a solder resist width of  $\geq 0.17$ mm remains.
- The land pad should be Solder Mask Defined (SMD), with a minimum overlap of the solder resist onto the copper of 0.06mm to accommodate solder resist mis-alignment. In 0.5mm pitch cases it is allowable to have the solder resist opening for the land pad to be smaller than the part pad.
- Ensure that the solder resist in-between the lead lands and the pad land is ≥ 0.15mm due to the high aspect ratio of the solder resist strip separating the lead lands from the pad land.
- The four vias in the land pad should be tented or plugged from bottom board side with solder resist.





PCB Solder Resist

### **Stencil Design**

- The stencil apertures for the lead lands should be approximately 80% of the area of the lead lands. Reducing the amount of solder deposited will minimize the occurrence of lead shorts. Since for 0.5mm pitch devices the leads are only 0.25mm wide, the stencil apertures should not be made narrower; openings in stencils < 0.25mm wide are difficult to maintain repeatable solder release.
- The stencil lead land apertures should therefore be shortened in length by 80% and centered on the lead land.
- The land pad aperture should be striped with 0.25mm wide openings and spaces to deposit approximately 50% area of solder on the center pad. If too much solder is deposited on the center pad the part will float and the lead lands will be open.
- The maximum length and width of the land pad stencil aperture should be equal to the solder resist opening minus an annular 0.2mm pull back to decrease the incidence of shorting the center land to the lead lands when the part is pushed into the solder paste.



Stencil Aperture All Dimensions in mm

# **APPLICATIONS PACKAGE INFORMATION**



 $\overline{\mathsf{G}}$ 

L

 $\overline{R}$ 

 $0.30$ 

### **32L MLPQ (5 x 5 mm Body)**  $- θ_{JA} = 22.4 °C/W$ **,**  $θ_{JC} = 0.86 °C/W$

Data and specifications subject to change without notice. This product has been designed and qualified for the Consumer market. Qualification Standards can be found on IR's Web site.

> International **IGR** Rectifier

**IR WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7903 Visit us at www.irf.com for sales contact information**.** www.irf.com

0.55 REF

 $0.40$ 

 $0.125$  TYP

0.50

www.irf.com

单击下面可查看定价,库存,交付和生命周期等信息

[>>Infineon\(英飞凌\)](https://www.oneyac.com/brand/990.html)